AeroBase Group

View Online at https://aerobasegroup.com/nsn/5961-01-105-8549

nclosure Material:	
Ceramic	
Overall Length:	
Between 0.660 inches and	1 0.785 inches
Overall Height:	
0.325 inches	
Overall Width:	
0.325 inches	
Component Name And G	luantity:
4 transistor	
Mounting Method:	
Press fit	
Features Provided:	
Hermetically sealed case	
Semiconductor Material	
Silicon all transistor	
Voltage Rating In Volts F	Per Characteristic:
70.0 collector to base vol	tage, dc all transistor and 445.0 collector to emitter voltage, dc all transistor and 6.0 emitter to base voltage, dc
all transistor	
Current Rating Per Char	acteristic:
1.50 amperes source cuto	ff current all transistor
Maximum Operating Ten	npurature Per Measurement Point:
200.0 degrees celsius june	ction
Special Features:	
All transistor junction patte	ern arrangement: npn
Terminal Type And Quar	ntity:
14 ribbon	
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
No	
Fiig:	
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